

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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UNR52A0G

Silicon NPN epitaxial planar type

For digital circuits

■ Features

- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.
- SMini type package allowing easy automatic insertion through tape packing

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V _{CBO} | 50 | V | |
| Collector-emitter voltage (Base open) | V _{CEO} | 50 | V | |
| Collector current | I_{C} | 80 | mA | |
| Total power dissipation | P_{T} | 150 | mW | |
| Junction temperature | T _j | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

■ Package

- Code
 - SMini3-F2
- Pin Name
 - 1: Base
 - 2: Emitter
 - 3: Collector

■ Marking Symbol: KT

■ Internal Connection

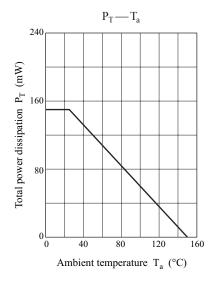
$$B \circ \xrightarrow{R_1 (47 \text{ k}\Omega)} C$$

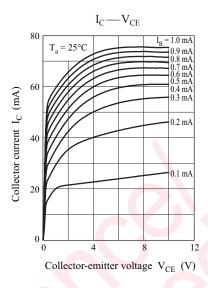
■ Electrical Characteristics $T_a = 25$ °C±3°C

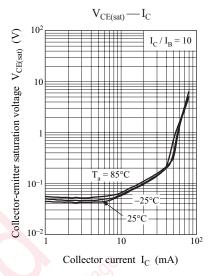
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|--|------|-----|------|------|
| Collector-base voltage (Emitter open) | V _{CBO} | $I_C = 10 \mu A, I_E = 0$ | 50 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$ | 50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{\rm CB} = 50 \text{ V}, I_{\rm E} = 0$ | | | 0.1 | μΑ |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = 50 \text{ V}, I_{B} = 0$ | | | 0.5 | μΑ |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = 6 \text{ V}, I_{C} = 0$ | | | 0.01 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$ | 160 | | 460 | _ |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA}$ | | | 0.25 | V |
| Output voltage high-level | V _{OH} | $V_{CC} = 5 \text{ V}, V_{B} = 0.5 \text{ V}, R_{L} = 1 \text{ k}\Omega$ | 4.9 | | | V |
| Output voltage low-level | V _{OL} | $V_{CC} = 5 \text{ V}, V_{B} = 2.5 \text{ V}, R_{L} = 1 \text{ k}\Omega$ | | | 0.2 | V |
| Input resistance | R ₁ | | -30% | 47 | +30% | kΩ |
| Transition frequency | f_T | $V_{CB} = 10 \text{ V}, I_{E} = -2 \text{ mA}, f = 200 \text{ MHz}$ | | 150 | | MHz |

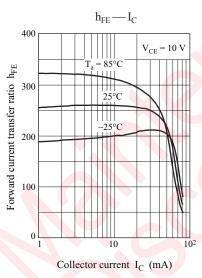
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

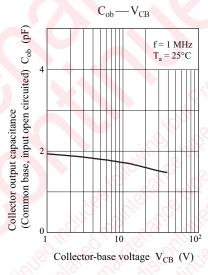
UNR52A0G Panasonic

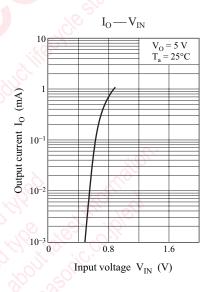


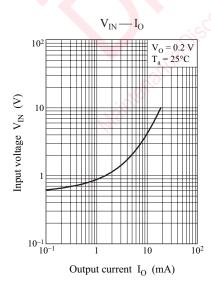




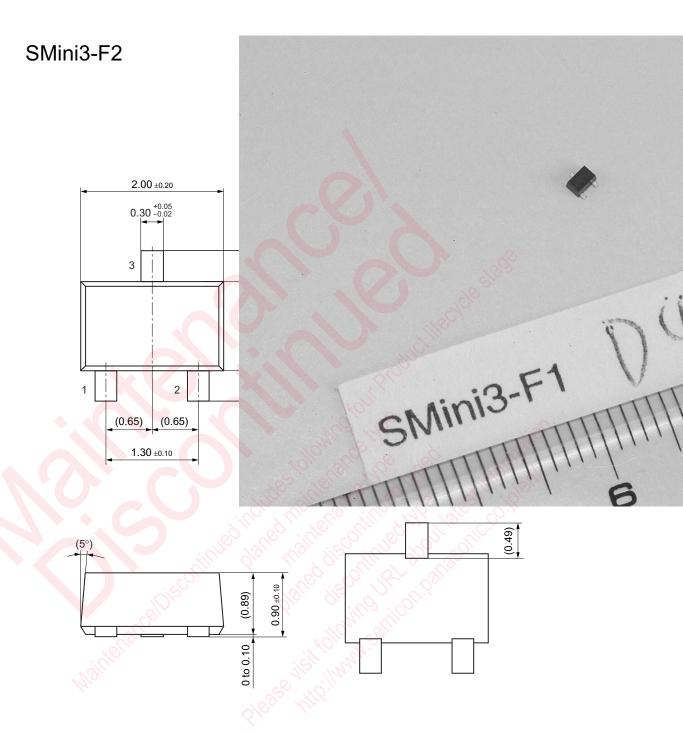








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